

CMOS Digital Integrated Circuits Silicon Monolithic

7UL1G17FS

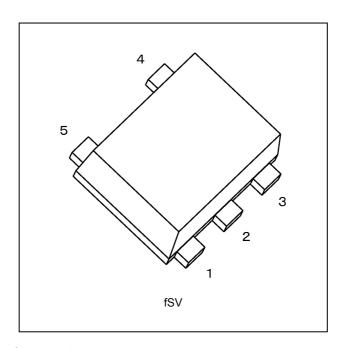
1. Functional Description

· Schmitt Buffer

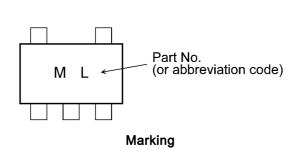
2. Features

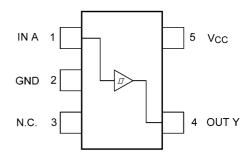
- (1) Wide operating temperature range: $T_{opr} = -40$ to 125 °C
- (2) High output current: ± 8.0 mA (min) at $V_{CC} = 3.0$ V
- (3) Super high speed operation: $t_{pd} = 3.0$ ns (typ.) at $V_{CC} = 3.3$ V, $C_L = 15$ pF
- (4) Operation voltage range: $V_{CC} = 0.9 \text{ to } 3.6 \text{ V}$
- (5) 3.6 V tolerant inputs
- (6) 3.6 V power down protection output

3. Packaging



4. Marking and Pin Assignment





Pin Assignment (Top view)

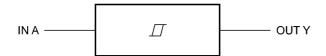
Start of commercial production

2018-10

Downloaded from Arrow.com.



5. IEC Logic Symbol



6. Truth Table

Input A	Output Y
L	L
Н	Н

7. Absolute Maximum Ratings (Note) (Unless otherwise specified, T_a = 25 °C)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V _{CC}		-0.5 to 4.6	V
Input voltage	V _{IN}		-0.5 to 4.6	V
DC output voltage	V _{OUT}	(Note 1)	-0.5 to 4.6	V
		(Note 2)	-0.5 to V _{CC} + 0.5	
Input diode current	I _{IK}		-20	mA
Output diode current	I _{OK}	(Note 3)	-20	mA
DC output current	I _{OUT}		±25	mA
V _{CC} /ground current	I _{CC}		±50	mA
Power dissipation	P _D		50	mW
Storage temperature	T _{stg}		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: $V_{CC} = 0 V$

Note 2: High (H) or Low (L) state. I_{OUT} absolute maximum rating must be observed.

Note 3: V_{OUT} < GND



8. Operating Ranges (Note)

Characteristics	Symbol	Note	Test Condition	Rating	Unit
Supply voltage	V _{CC}		_	0.9 to 3.6	V
Input voltage	V _{IN}		_	0 to 3.6	V
Output voltage	V _{OUT}	(Note 1)	_	0 to 3.6	V
		(Note 2)	_	0 to V _{CC}	
Output current	I _{OH} ,I _{OL}		V _{CC} = 3.0 to 3.6 V	±8.0	mA
			V _{CC} = 2.3 to 2.7 V	±4.0	
			V _{CC} = 1.65 to 1.95 V	±3.0	
			V _{CC} = 1.4 to 1.6 V	±1.7	
			V _{CC} = 1.1 to 1.3 V	±0.3	
			V _{CC} = 0.9 V	±0.02	
Operating temperature	T _{opr}		_	-40 to 125	°C

Note: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either $V_{\mbox{\footnotesize CC}}$ or GND.

Note 1: $V_{CC} = 0 V$

Note 2: High (H) or Low (L) state.



9. Electrical Characteristics

9.1. DC Characteristics (Unless otherwise specified, T_a = 25 °C)

Characteristics	Symbol	Test Condition	1	V _{CC} (V)	Min	Тур.	Max	Unit
Positive threshold voltage	V _P	_		0.9	_	I	0.73	V
				1.1	_		0.86	
				1.4	_	I	1.07	
				1.65	_		1.23	
				2.3	_	_	1.66	
				3.0	_	_	2.14	
Negative threshold voltage	V _N	_		0.9	0.18		_	V
				1.1	0.26	_	_	
				1.4	0.36	_	_	
				1.65	0.45	_	_	
				2.3	0.69	-	_	
				3.0	0.96	_	_	
Hysteresis voltage	V _H	_		0.9	0.15	_	0.38	V
				1.1	0.18	-	0.41	
				1.4	0.20	_	0.48	
				1.65	0.22		0.60	
				2.3	0.35		0.76	
				3.0	0.45	_	0.93	
High-level output voltage	V _{OH}	$V_{IN} = V_{IH}$	I _{OH} = -0.02 mA	0.9	0.75		_	V
			I _{OH} = -0.3 mA	1.1 to 1.3	V _{CC} × 0.75	_	_	
			I _{OH} = -1.7 mA	1.4 to 1.6	V _{CC} × 0.75	_	_	
			I _{OH} = -3.0 mA	1.65 to 1.95	V _{CC} -0.45	_	_	
			I _{OH} = -4.0 mA	2.3 to 2.7	2.0	_	_	
			I _{OH} = -8.0 mA	3.0 to 3.6	2.48	_	_	
Low-level output voltage	V _{OL}	$V_{IN} = V_{IL}$	I _{OL} = 0.02 mA	0.9	_	_	0.1	V
			I _{OL} = 0.3 mA	1.1 to 1.3	_	_	$V_{CC} \times 0.25$	
			I _{OL} = 1.7 mA	1.4 to 1.6	_	_	$V_{CC} \times 0.25$	
			I _{OL} = 3.0 mA	1.65 to 1.95	_	_	0.45	
			I _{OL} = 4.0 mA	2.3 to 2.7	_	_	0.4	
			I _{OL} = 8.0 mA	3.0 to 3.6	_	_	0.4	
Input leakage current	I _{IN}	V _{IN} = 0 to 3.6 V	-	0 to 3.6	_	_	±0.1	μА
Power-OFF leakage current	I _{OFF}	V _{IN} = 0 to 3.6 V, V _{OUT} = 0 to 3.6 V		0	_	_	1.0	μА
Quiescent supply current	Icc	$V_{IN} = V_{CC}$ or GND		3.6	_	_	1.0	μА



9.2. DC Characteristics (Unless otherwise specified, T_a = -40 to 85 °C)

Characteristics	Symbol	Test Condition	on	V _{CC} (V)	Min	Max	Unit
Positive threshold voltage	V _P	_	0.9	_	0.73	V	
				1.1	_	0.86	
				1.4	_	1.07	
				1.65	_	1.23	
				2.3	_	1.66	
				3.0	_	2.14	
Negative threshold voltage	V _N	_		0.9	0.18	_	V
				1.1	0.26	_	
				1.4	0.36	_	
				1.65	0.45	_	
				2.3	0.69	_	
				3.0	0.96	_	
Hysteresis voltage	V _H	_		0.9	0.15	0.38	V
				1.1	0.18	0.41	
				1.4	0.20	0.48	
				1.65	0.22	0.60	
				2.3	0.35	0.76	
				3.0	0.45	0.93	
High-level output voltage	V _{OH}	V _{IN} = V _{IH}	I _{OH} = -0.02 mA	0.9	0.75	_	V
			$I_{OH} = -0.3 \text{ mA}$	1.1 to 1.3	V _{CC} × 0.75	_	
			I _{OH} = -1.7 mA	1.4 to 1.6	V _{CC} × 0.75	_	
			I _{OH} = -3.0 mA	1.65 to 1.95	V _{CC} -0.45	_	
			I _{OH} = -4.0 mA	2.3 to 2.7	2.0	_	
			I _{OH} = -8.0 mA	3.0 to 3.6	2.48	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IL}	I _{OL} = 0.02 mA	0.9	_	0.1	V
			$I_{OL} = 0.3 \text{ mA}$	1.1 to 1.3	_	V _{CC} × 0.25	
			I _{OL} = 1.7 mA	1.4 to 1.6	_	V _{CC} × 0.25	
			I _{OL} = 3.0 mA	1.65 to 1.95	_	0.45	
			I _{OL} = 4.0 mA	2.3 to 2.7	_	0.4	
			I _{OL} = 8.0 mA	3.0 to 3.6	_	0.4	
Input leakage current	I _{IN}	V _{IN} = 0 to 3.6 V		0 to 3.6	_	±0.5	μА
Power-OFF leakage current	I _{OFF}	V _{IN} = 0 to 3.6 V, V _{OUT} = 0 to 3.6 V		0	_	10.0	μА
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		3.6	_	10.0	μΑ



9.3. DC Characteristics (Unless otherwise specified, T_a = -40 to 125 °C)

Characteristics	Symbol	Test Condition	on	V _{CC} (V)	Min	Max	Unit
Positive threshold voltage	V _P	_	0.9	_	0.73	V	
				1.1	_	0.86	
				1.4	_	1.07	
				1.65	_	1.23	
				2.3	_	1.66	
				3.0	_	2.14	
Negative threshold voltage	V _N	_		0.9	0.18	_	V
				1.1	0.26	_	
				1.4	0.36	_	
				1.65	0.45	_	
				2.3	0.69	_	
				3.0	0.96	_	
Hysteresis voltage	V _H	_		0.9	0.15	0.38	V
				1.1	0.18	0.41	
				1.4	0.20	0.48	
				1.65	0.22	0.60	
				2.3	0.35	0.76	
				3.0	0.45	0.93	
High-level output voltage	V _{OH}	$V_{IN} = V_{IH}$	I _{OH} = -0.02 mA	0.9	0.75	_	V
			I _{OH} = -0.3 mA	1.1 to 1.3	V _{CC} × 0.73	_	
			I _{OH} = -1.7 mA	1.4 to 1.6	V _{CC} × 0.73	_	
			I _{OH} = -3.0 mA	1.65 to 1.95	V _{CC} -0.5	_	
			I _{OH} = -4.0 mA	2.3 to 2.7	1.95	_	
			I _{OH} = -8.0 mA	3.0 to 3.6	2.4	_	
Low-level output voltage	V _{OL}	$V_{IN} = V_{IL}$	I _{OL} = 0.02 mA	0.9	_	0.1	V
			I _{OL} = 0.3 mA	1.1 to 1.3	_	V _{CC} × 0.27	
			I _{OL} = 1.7 mA	1.4 to 1.6	_	V _{CC} × 0.27	
			I _{OL} = 3.0 mA	1.65 to 1.95	_	0.5	
			I _{OL} = 4.0 mA	2.3 to 2.7	_	0.45	
			I _{OL} = 8.0 mA	3.0 to 3.6	_	0.45	
Input leakage current	I _{IN}	V _{IN} = 0 to 3.6 V		0 to 3.6	_	±2.0	μА
Power-OFF leakage current	I _{OFF}	V _{IN} = 0 to 3.6 V, V _{OUT} = 0 to 3.6 V		0	_	80.0	μА
Quiescent supply current	Icc	V _{IN} = V _{CC} or GND		3.6		80.0	μА

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9.4. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Unit
Propagation delay time	t _{PLH} ,t _{PHL}		$R_L = 1 M\Omega$	0.9	10	_	22.0	_	ns
				1.1 to 1.3		-	11.1	22.6	
				1.4 to 1.6		_	6.7	10.5	
				1.65 to 1.95		-	5.0	7.8	
				2.3 to 2.7		_	3.3	5.4	
				3.0 to 3.6		-	2.7	4.4	
Propagation delay time	t _{PLH} ,t _{PHL}		$R_L = 1 M\Omega$	0.9	15	-	24.2	_	ns
				1.1 to 1.3		-	12.1	25.1	
				1.4 to 1.6		_	7.3	11.5	
				1.65 to 1.95		-	5.5	8.4	
				2.3 to 2.7		_	3.7	5.7	
				3.0 to 3.6		_	3.0	4.6	
Propagation delay time	t _{PLH} ,t _{PHL}		$R_L = 1 M\Omega$	0.9	30	_	31.0	_	ns
				1.1 to 1.3		_	15.7	35.7	
				1.4 to 1.6		-	9.1	15.8	
				1.65 to 1.95		_	7.1	10.7	
				2.3 to 2.7		_	4.7	6.9	
				3.0 to 3.6		_	3.9	5.2	
Input capacitance	C _{IN}		_	3.6	_		3	_	pF
Power dissipation capacitance	C _{PD}	(Note 1)	_	0.9 to 3.6	_	_	9	_	pF

Note 1: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation. $I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

9.5. AC Characteristics (Unless otherwise specified, T_a = -40 to 85 °C, Input: t_r = t_f = 3 ns)

Characteristics	Symbol	Test Condition	V _{CC} (V)	C _L (pF)	Min	Max	Unit
Propagation delay time	t _{PLH} ,t _{PHL}	$R_L = 1 M\Omega$	0.9	10	_	_	ns
			1.1 to 1.3		1.0	35.9	
			1.4 to 1.6		1.0	11.3	
			1.65 to 1.95		1.0	8.2	
			2.3 to 2.7		1.0	5.8	
			3.0 to 3.6		1.0	4.6	
Propagation delay time	t _{PLH} ,t _{PHL}	$R_L = 1 M\Omega$	0.9	15	_	_	ns
			1.1 to 1.3		1.0	41.8	
			1.4 to 1.6		1.0	12.6	
			1.65 to 1.95		1.0	8.7	
			2.3 to 2.7		1.0	6.1	
			3.0 to 3.6		1.0	5.0	
Propagation delay time	t _{PLH} ,t _{PHL}	$R_L = 1 M\Omega$	0.9	30	_	_	ns
			1.1 to 1.3		1.0	58.1	
			1.4 to 1.6		1.0	17.6	
			1.65 to 1.95		1.0	11.7	
			2.3 to 2.7		1.0	8.1	
			3.0 to 3.6		1.0	6.1	



9.6. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 125 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	V _{CC} (V)	C _L (pF)	Min	Max	Unit
Propagation delay time	t _{PLH} ,t _{PHL}	$R_L = 1 M\Omega$	0.9	10	_	_	ns
			1.1 to 1.3		1.0	44.8	
			1.4 to 1.6]	1.0	11.9	
			1.65 to 1.95		1.0	8.5	
			2.3 to 2.7		1.0	6.1	
			3.0 to 3.6]	1.0	4.8	
Propagation delay time	t _{PLH} ,t _{PHL}	$R_L = 1 M\Omega$	0.9	15	_	_	ns
			1.1 to 1.3		1.0	53.0	
			1.4 to 1.6]	1.0	13.4	
			1.65 to 1.95		1.0	8.9	
			2.3 to 2.7		1.0	6.4	
			3.0 to 3.6		1.0	5.3	
Propagation delay time	t _{PLH} ,t _{PHL}	$R_L = 1 M\Omega$	0.9	30	_	_	ns
			1.1 to 1.3		1.0	73.1	
			1.4 to 1.6		1.0	18.8	
			1.65 to 1.95]	1.0	12.4	
			2.3 to 2.7]	1.0	8.9	
			3.0 to 3.6		1.0	6.7	

9.7. AC Waveform

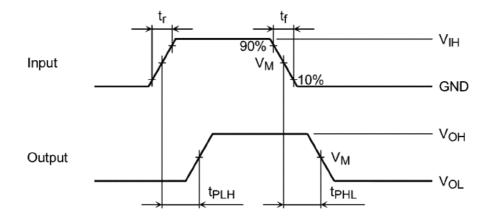


Fig. 9.7.1 t_{PLH}, t_{PHL}

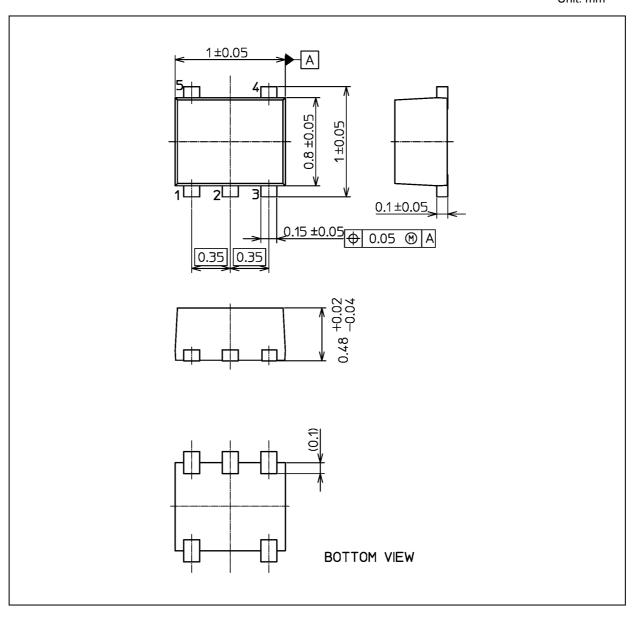
Table 9.7.1 AC Waveform Symbols

	Symbol	V _{CC} = 3.3 ± 0.3 V	V _{CC} = 2.5 ± 0.2 V	V _{CC} = 1.8 ± 0.15 V	V _{CC} = 1.5 ± 0.1 V	V _{CC} = 1.2 ± 0.1 V	V _{CC} = 0.9 V
Input	V _{IN}	V _{CC}	V _{CC}	V_{CC}	V _{CC}	V _{CC}	V _{CC}
	V _M	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2
Output	V _M	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2



Package Dimensions

Unit: mm



Weight: 1.0 mg (typ.)

	Package Name(s)	
Nickname: fSV		

Rev.3.0



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